MIC94030/94031



TinyFET® P-Channel MOSFET

General Description

The MIC94030 and MIC94031 are 4-terminal silicon gate P-channel MOSFETs that provide low on-resistance in a very small package.

Designed for high-side switch applications where space is critical, the MIC94030/1 exhibits an on-resistance of typically 0.75 Ω at 4.5V gate-to-source voltage. The MIC94030/1 also operates with only 2.7V gate-to-source voltage.

The MIC94030 is the basic 4-lead P-channel MOSFET. The MIC94031 is a variation that includes an internal gate pull-up resistor that can reduce the system parts count in many applications.

The 4-terminal SOT-143 package permits a substrate connection separate from the source connection. This 4-terminal configuration improves the θ_{JA} (improved heat dissipation) and makes analog switch applications practical.

The small size, low threshold, and low $R_{\text{DS(on)}}$ make the MIC94030/1 the ideal choice for PCMCIA card sleep mode or distributed power management applications.

Features

- 13.5V minimum drain-to-source breakdown
- 0.75Ω typical on-resistance
 - at 4.5V gate-to-source voltage
- 0.45Ω typical on-resistance
 - at 10V gate-to-source voltage
- Operates with 2.7V gate-to-source voltage
- · Separate substrate connection for added control
- Industry's smallest surface mount package

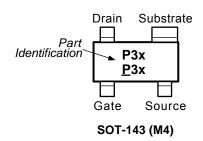
Applications

- · Distributed power management
- · PCMCIA card power management
- · Battery-powered computers, peripherals
- Hand-held bar-code scanners
- Portable communications equipment

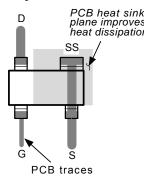
Ordering Information

Part Number			Junction Temp. Range	Package		
Standard	Marking	Pb-Free	Marking	Junction Temp. Range	rackaye	
MIC94030BM4	P30	MIC94030YM4	<u>P</u> 30	–55° to +150°C	SOT-143	
MIC94031BM4	P31	MIC94031YM4	<u>P</u> 31	–55° to +150°C	SOT-143	

Pin Configuration



Typical PCB Layout



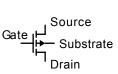
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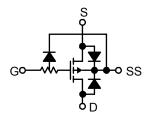
Schematic Symbol

Functional Diagrams

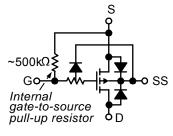




Schematic Symbol







MIC94031

Absolute Maximum Ratings⁽¹⁾

Voltage and current values are negative. Signs not shown t	or clarity.
Drain-to-Source Voltage (pulse)	16V
Gate-to-Source Voltage (pulse).	16V
Continuous Drain Current	
T _A = 25°C	1A
T _A = 100°C	
Operating Junction Temperature–55°C to	+150°C
Storage Temperature–55°C to	+150°C

Total Power Dissipation	
T _A = 25°C	568mW
T _A = 100°C	
Thermal Resistance	
θ_{JA}	220°C/W
θ _{JC}	130°C/W
Lead Temperature	
1/16" from case, 10s	+300°C

Electrical Characteristics

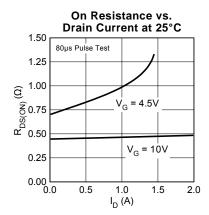
Voltage and current values are negative. Signs not shown for clarity.

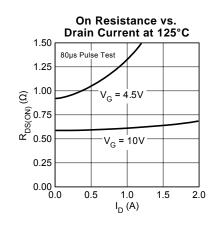
Symbol	Parameter	Condition (Note 1)	Min	Тур	Max	Units
V _{BDSS}	Drain-Source Breakdown Voltage	V _{GS} = 0V, I _D = 250μA	13.5			V
V _{GS}	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_D = 250 \mu A$	0.6	1.0	1.4	V
I _{GSS}	Gate-Body Leakage	V _{DS} = 0V, V _{GS} = 12V, Note 2, Note 3			1	μA
R _{GS}	Gate-Source Resistor	V _{DS} = 0V, V _{GS} = 12V, Note 2, Note 4	500	750	1000	kΩ
C _{ISS}	Input Capacitance	V _{GS} = 0V, V _{DS} = 12V		100		pF
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = 12V, V _{GS} = 0V			25	μA
		V _{DS} = 12V, V _{GS} = 0V, T _J = 125°C		0.010	250	μA
I _{D(ON)}	On-State Drain Current	V _{DS} = 10V, V _{GS} = 10V, Note 5		6.3		Α
R _{DS(ON)}	Drain-Source On-State Resist	$V_{GS} = 10V, I_D = 100mA$ $V_{GS} = 4.5V, I_D = 100mA$ $V_{GS} = 2.7V, I_D = 100mA$		0.45 0.75 1.20	1.00	Ω Ω Ω
g FS	Forward Transconductance	V _{DS} = 10V, I _D = 200mA, Note 5		480		mS

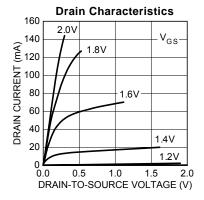
Notes:

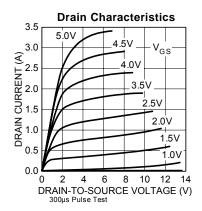
- 1. $T_A = 25$ °C unless noted. Substrate connected to source for all conditions.
- 2. ESD gate protection diode conducts during positive gate-to-source voltage excursions.
- 3. MIC94030 only.
- 4. MIC94031 only.
- 5. Pulse Test: Pulse Width ≤ 80µsec, Duty Cycle ≤ 0.5%.

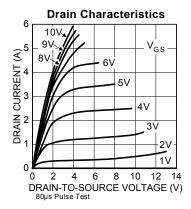
Typical Characteristics











Typical Applications

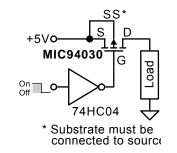


Figure 1. Power Switch Application

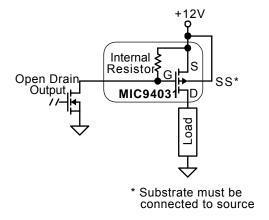


Figure 2. Power Control Application

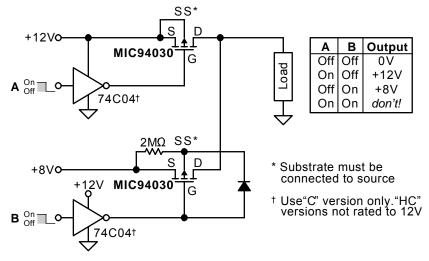
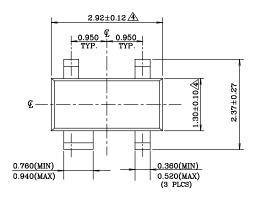
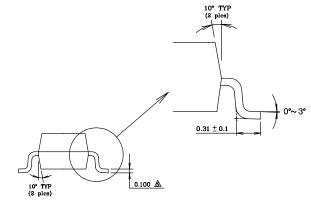


Figure 3. Analog Switch Application

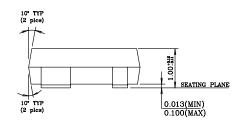
Package Information



TOP VIEW



END VIEW



SIDE VIEW

NOTE:

- 1. Dimensions and tolerances are as per ANSI Y14.5M, 1982.
- 2. Package surface to be mirror finish.
- 3. Die is facing up for mold & trim/form.
- Dimension are exclusive of mold flash and gate burr.
- 5 Dimension are exclusive of solder plating.

SOT-143 (M4)

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